NSN 5961-01-226-6062

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-226-6062

Inclosure Material:

Metal

Overall Length:

1.252 inches

Overall Height:

0.340 inches

Overall Width:

0.700 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-66

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

1200.0 collector-to-emitter, with voltage between base and emitter and 750.0 collector-to-emitter, substaining voltage, base open-circuited

and 5.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

7.00 amperes source cutoff current and 4.00 amperes source cutoff current

Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector absolute

Transfer Ratio:

20.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0